FTR05086-001b

### Ultra-Low Quiescent Current, Inductor Built-in Step-Down DC/DC Converter

☆Green Operation compatible

### ■GENERAL DESCRIPTION

The XCL232 series is a synchronous step-down micro DC/DC converter which integrates an inductor and a control IC in one tiny package. It uses an ultra-low current consumption circuit and PFM control. The control IC and coil are integrated to achieve miniaturization, and a space-saving power supply can be configured simply by adding two external capacitors. In addition, the ultra-low current consumption circuit and PFM control method realize high efficiency with a light load.

A operating voltage range of 1.8V to 6.0V enables support for applications that require an internally fixed output voltage from 0.5V to 3.6V.

It has a built-in UVLO function, the internal P-channel driver FET and N-channel driver FET are turned OFF when input voltage is below to the UVLO detection voltage. The D type integrate CL discharge function which enables the electric charge at the output capacitor CL to be discharged via the internal discharge switch located between the VOUT and GND. When the devices enter stand-by mode, output voltage quickly returns to the GND level as a result of this function.

### APPLICATIONS

- Smart meter
- Low Power RF
- Sensor Module
- Wearable Devices
- **Energy Harvest devices**
- Back-up power supply circuit
- Smart card
- Devices with 1 Lithium cell

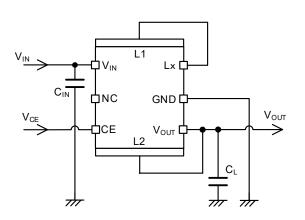
FEATURES	
Input Voltage Range	

Output Voltage Setting	:	0.5V ~ 1.9V (0.05V increments)
		2.0V ~ 3.6V (0.1V increments)
Output Voltage Accuracy		±20mV (V <sub>OUT1-2</sub> ≦1.0V)
		±2.0% (V <sub>OUT1-2</sub> >1.0V)
Output Current	:	150mA
Supply Current	:	200nA @ Vout=1.8V
Control Method	:	PFM control
Efficiency	:	86% (V <sub>IN</sub> =3.6V, Vout=1.8V, Iout=10mA)
Function	:	C∟Discharge (D Type)
		UVLO function
Protection Functions	:	Short Protection
Input / Output Capacitor	:	Ceramic Capacitor Compatible
Operation Ambient Temperature	:	-40 ~ 85°C
Package	:	CL-2025-03 (2.5 x 2.0 x 1.04mm)
Environmentally Friendly		EU RoHS compliant, Pb Free

1.8V ~ 6.0V

## ■ TYPICAL APPLICATION CIRCUIT

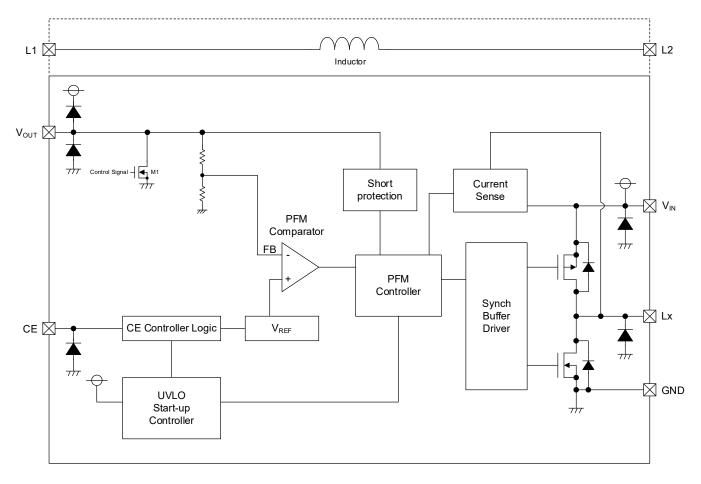
## ■TYPICAL PERFORMANCE CHARACTERISTICS



#### Vout=1.8V C<sub>IN</sub> = LMK107BBJ106MA(10µF/10V) $C_1 = JMK107BBJ226MA(22\mu F/6.3V)$ 100 90 80 Efficiency: EFFI (%) 70 VIN = 5.0V 60 -- VIN = 4.2V 50 - · - VIN = 3.3V 40 30 20 10 Λ 0.001 0.01 0.1 1 10 100 Output Current: IOUT (mA)

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## ■ BLOCK DIAGRAM



\* Diodes inside the circuits are ESD protection diodes and parasitic diodes. XCL232B type does not have  $C_L$  Discharge function.

## ■ PRODUCT CLASSIFICATION

### 1) Ordering information

XCL232(12)3(45)6-7)

DESIGNATOR	ITEM	SYMBOL	DESCRIPTION
	Draduat Type	В	Without C∟ Discharge
1	Product Type	D	With C <sub>L</sub> Discharge
23	Output Voltage	05 ~ 36	Output Voltage options   e.g.) 1.2V → ② = 1 ③ = 2   1.25V → ② = 1 ③ = C   0.05V increments :   0.05=A, 0.15=B, 0.25=C, 0.35=D, 0.45=E,   0.55=F, 0.65=H, 0.75=K, 0.85=L, 0.95=M   (Vout≤1.9V : 0.05V increments,   Vout>1.9V : 0.1V increments)
4	Fixed number	1	Fixed number
(5)6-7 (*1)	Packages (Order Unit)	KR-G	CL-2025-03 <sup>(*2)</sup> (3,000pcs/Reel)

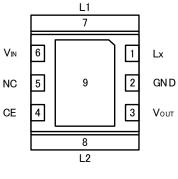
<sup>(\*1)</sup> The "-G" suffix denotes Halogen and Antimony free as well as being fully EU RoHS compliant.

(\*2) CL-2025-03 Reels are shipped in moisture-proof packaging.

#### 2) Selection Guide

FUNCTION	B T`	YPE	YPE			
FUNCTION	V <sub>OUT(T)</sub> <1.2V	$V_{OUT(T)} \ge 1.2V$	V <sub>OUT(T)</sub> <1.2V	$V_{OUT(T)} \ge 1.2V$		
Short Protection	-	Yes	-	Yes		
C∟ Discharge	- Yes					
Chip Enable	Yes					
UVLO	Yes					

## ■ PIN CONFIGURATION



#### < BOTTOM VIEW >

## ■ PIN ASSIGNMENT

PIN NUMBER	PIN NAME	FUNCTION
1	Lx	Switching
2	GND	Ground
3	V <sub>OUT</sub>	Output Voltage
4	CE	Chip Enable
5	NC	No Connection
6	VIN	Input Voltage
7	L1	Inductor Electrodes
8	L2	Inductor Electrodes
9	EP	Exposed thermal pad. The Exposed pad must be connected to GND(Pin2).

## ■ FUNCTION

PIN NAME	SIGNAL	STATUS
	Н	Active
CE	L	Stand-by
	OPEN	Undefined State (*1)

(\*1) Please do not leave the CE pin open.

## ■ABSOLUTE MAXIMUM RATINGS

			Ta=25°C
PARAMETER	SYMBOL	RATINGS	UNITS
V <sub>IN</sub> Pin Voltage	VIN	-0.3 ~ 7.0	V
Lx Pin Voltage	V <sub>LX</sub>	-0.3 ~ V <sub>IN</sub> + 0.3 or 7.0 $^{(*1)}$	V
Vout Pin Voltage	Vout	-0.3 ~ V <sub>IN</sub> + 0.3 or 7.0 $^{(*1)}$	V
CE Pin Voltage	VCE	-0.3 ~ 7.0	V
Power Dissipation	Pd	800 (40 x 40mm Standard board) $(*2)$	mW
Junction Temperature	Tj	-40 ~ 125	°C
Storage Temperature	Tstg	-55 ~ 125	C°

\* All voltages are described based on the GND pin.

 $^{(^{\ast}1)}$  The maximum value should be either V\_IN+0.3V or 7.0V in the lowest.

(\*2) The power dissipation figure shown is PCB mounted and is for reference only.

Please refer to PACKAGING INFORMATION for the mounting condition.

### ■RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS
V <sub>IN</sub> Pin Voltage	Vin	1.8	~	6.0	V
Iout Current	Іоит	0	~	150	mA
CE Pin Voltage	VCE	0.0	~	6.0	V
Operating Ambient Temperature	Topr	-40	~	85	°C
Junction Temperature	Tj	-40	~	105	C°

\* All voltage operating condition is based on the GND pin.

## ■ELECTRICAL CHARACTERISTICS

							Ta=25℃
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS	CIRCUIT
Output Voltage <sup>(*1)</sup>	V <sub>OUT1</sub>	When connected to external components, I <sub>OUT</sub> = 30mA	-	<t-1></t-1>	-	V	1
Output Voltage1-2	V <sub>OUT1-2</sub>	Voltage which $L_X$ pin changes "H" to "L" level while $V_{\text{OUT}}$ is increase. $^{(5)}$	<e-1></e-1>	<e-2></e-2>	<e-3></e-3>	v	2
Operating Voltage Range	Vin	-	1.8	-	6.0	V	1
Maximum Output Current	Ioutmax	When connected to external components (*2)	150	-	-	mA	1
UVLO Release Voltage	Vuvlor	$V_{OUT} = 0.0V, V_{CE} = 1.8V$ Ta=25°C     Voltage which Lx pin holding "H" level <sup>(*5)</sup> Ta=-40~85°C <sup>(*3)</sup>		1.50	1.78	v	2
UVLO Detect Voltage	Vuvlod	$V_{OUT} = 0.0V, V_{CE} = 1.8V$ Ta=25°C     Voltage which Lx pin holding "L" level <sup>(*5)</sup> Ta=-40~85°C <sup>(*3)</sup>	- 1.00	1.40	-	v	2
Quiescent Current	lq	V <sub>IN</sub> = V <sub>CE</sub> = <c-1>, V<sub>OUT</sub> = V<sub>OUT1</sub>×1.05</c-1>	-	<e-4></e-4>	<e-5></e-5>	nA	3
Stand-by Current	I <sub>STB</sub>	$V_{IN}$ = 6.0V, $V_{CE}$ = $V_{OUT}$ =0.0V	-	0.0	0.1	μA	3
PFM Switching Current	IPFM	When connected to external components, $V_{IN} = V_{OUT(T)} + 2.0V$ , $I_{OUT} = 10mA$	-	400	600	mA	1
Lx SW "H" ON Resistance	R <sub>LXH</sub>	$V_{\text{OUT}}$ = 0.0V, $V_{\text{IN}}$ = $V_{\text{CE}}$ = 5.0V, ILx = 50mA	-	0.40	0.50	Ω	4
Lx SW "L" ON Resistance(*3)	R <sub>LXL</sub>	V <sub>IN</sub> = 5.0V	-	0.35	0.45	Ω	-
Lx SW "H" Leakage Current	I <sub>LeakH</sub>	$V_{\text{IN}}$ = 6.0V, $V_{\text{OUT}}$ = $V_{\text{CE}}$ = 0.0V , $VLx$ = 6.0V	-	0.0	0.1	μA	4
Lx SW "L" Leakage Current	I <sub>LeakL</sub>	$V_{\text{IN}}$ = 6.0V, $V_{\text{OUT}}$ = $V_{\text{CE}}$ = 0.0V , $VLx$ = 0.0V	-	0.0	0.1	μA	4
Output Voltage Temperature Characteristics	⊿Vout/ (Vout ∙⊿T₀pr)	$I_{OUT} = 30 \text{mA}$ -40°C $\leq$ Topr $\leq$ 85°C	-	±100	-	ppm/ ℃	1
CE "H" Voltage	V <sub>CEH</sub>	$V_{OUT} = 0.0V$ ,   Ta=25°C     Voltage which Lx pin holding "H" level <sup>(*5)</sup> Ta=-40~85°C <sup>(*3)</sup>	1.2	-	6.0	V	2
CE "L" Voltage	V <sub>CEL</sub>	V <sub>OUT</sub> = 0.0V,   Ta=25°C     Voltage which Lx pin holding "L" level(*5)   Ta=-40~85°C(*3)	GND	-	0.3	V	2
CE "H" Current	ICEH	$V_{IN}$ = 6.0V, $V_{OUT}$ = 0.0V, $V_{CE}$ = 6.0V	-0.1	0.0	0.1	μA	4
CE "L" Current	I <sub>CEL</sub>	$V_{IN} = 6.0V, V_{OUT} = 0.0V, V_{CE} = 0.0V$		0.0	0.1	μA	4
Short Protection Threshold Voltage <sup>(*4)</sup>	Vshort	$\label{eq:Voltage} Voltage which Lx pin holding "L" level ("5) \\ \hline Ta=-40 \sim 85^\circ C^{(*3)}$	0.10	0.54	0.80	V	2
C <sub>L</sub> Discharge (Type D)	RDCHG	V <sub>IN</sub> = 5.0V, V <sub>CE</sub> = 0.0V, V <sub>OUT</sub> =0.1V		45	60	Ω	2
Inductance Value	L	Test Frequency=1MHz		2.2	-	μH	
Inductor Rated Current	I <sub>DC_L</sub>	$\Delta T$ =+40 <sup>°</sup> C Current value that raises the temperature by 40 <sup>°</sup> C with DC current	-	850	-	mA	

Unless otherwise stated,  $V_{IN}$ =5V,  $V_{CE}$ =5V,  $V_{OUT(T)}$ =Nominal Value

(\*1) V<sub>OUT1</sub> are the average values of the output voltage considering the ripple voltage and they are set so that they can be a setting output voltage with this evaluation condition.

(\*2) The maximum output current performance varies based on a voltage difference between an input voltage and an output voltage, and external components and so on. Regarding detail of this variation, please refer to OPERATIONAL EXPLANATION and NOTE ON USE section.

(\*3) Design value

(\*4) SHORT PROTECTION with LATCH is not available if  $V_{\text{OUT1}}$  is 1.2V less than.

(\*5) "H" =  $V_{\text{IN}} \sim V_{\text{IN}}$  -1.2V, "L" = 0.1V  $\sim$  -0.1V

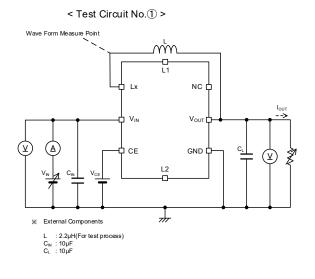
## ■ELECTRICAL CHARACTERISTICS

SPEC Table

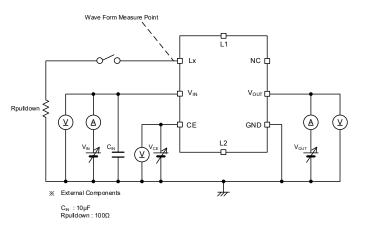
Nominal	V <sub>OUT1</sub> (V)	V <sub>OUT1-2</sub> (V)			V <sub>IN</sub> (V)	lq (	(nA)
Output Voltage	<t-1></t-1>	<e-1></e-1>	<e-2></e-2>	<e-3></e-3>	<c-1></c-1>	<e-4></e-4>	<e-5></e-5>
V <sub>OUT(T)</sub>	TYP.	MIN.	TYP.	MAX.	V <sub>IN</sub>	TYP.	MAX.
0.50	0.500	0.460	0.480	0.500	1.80	200	600
0.60	0.600	0.560	0.580	0.600	1.80	200	600
0.70	0.700	0.660	0.680	0.700	1.80	200	600
0.80	0.800	0.760	0.780	0.800	1.80	200	600
0.90	0.900	0.860	0.880	0.900	1.80	200	600
1.00	1.000	0.960	0.980	1.000	1.80	200	600
1.10	1.100	1.058	1.080	1.102	1.80	200	600
1.20	1.200	1.156	1.180	1.204	1.80	200	600
1.30	1.300	1.254	1.280	1.306	1.80	200	600
1.40	1.400	1.352	1.380	1.408	1.90	200	600
1.50	1.500	1.450	1.480	1.510	2.00	200	600
1.60	1.600	1.548	1.580	1.612	2.10	200	600
1.70	1.700	1.646	1.680	1.714	2.20	200	600
1.80	1.800	1.744	1.780	1.816	2.30	200	600
1.90	1.900	1.842	1.880	1.918	2.40	200	600
2.00	2.000	1.940	1.980	2.020	2.50	210	630
2.10	2.100	2.038	2.080	2.122	2.60	210	630
2.20	2.200	2.136	2.180	2.224	2.70	210	630
2.30	2.300	2.234	2.280	2.326	2.80	210	630
2.40	2.400	2.332	2.380	2.428	2.90	210	630
2.50	2.500	2.430	2.480	2.530	3.00	220	660
2.60	2.600	2.528	2.580	2.632	3.10	220	660
2.70	2.700	2.626	2.680	2.734	3.20	220	660
2.80	2.800	2.724	2.780	2.836	3.30	220	660
2.90	2.900	2.822	2.880	2.938	3.40	230	690
3.00	3.000	2.920	2.980	3.040	3.50	230	690
3.10	3.100	3.018	3.080	3.142	3.60	230	690
3.20	3.200	3.116	3.180	3.244	3.70	240	720
3.30	3.300	3.214	3.280	3.346	3.80	240	720
3.40	3.400	3.312	3.380	3.448	3.90	240	720
3.50	3.500	3.410	3.480	3.550	4.00	250	750
3.60	3.600	3.508	3.580	3.652	4.10	250	750

With regard to other voltage, please contact our sales representative.

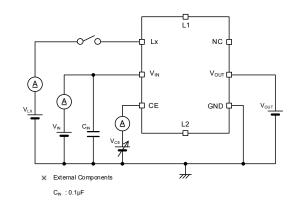
## TEST CIRCUITS



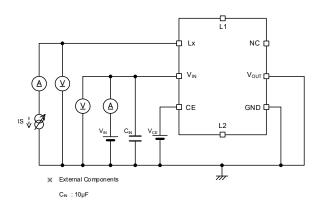
< Test Circuit No.2 >



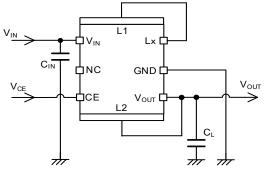
< Test Circuit No.④ >



< Test Circuit No.③ >



## ■TYPICAL APPLICATION CIRCUIT



(NOTES):

The coil is exclusively for this product.

Please do not use it for any purpose other than this product.

#### [Typical Examples]

	Manufacturer	Product Number	Value	Size
	Murata	GRM188R61A106ME69		
CIN	Taiyo Yuden	LMK107BBJ106MALT	10µF/10V	1.6 x 0.8 x 1.0mm
	TDK	C1608X5R1A106M		
	Murata	GRM188R61A106ME69	10µF/10V	
	Murata	GRM188R61A226ME15	22µF/10V	
	C∟ Taiyo Yuden	LMK107BBJ106MALT	10µF/10V	
CL		LMK107BBJ226MA	22µF/10V	1.6 x 0.8 x 1.0mm
		JMK107BBJ226MA	22µF/6.3V	
	TDK	C1608X5R1A106M	10µF/10V	
	IDK	C1608X5R1A226M	22µF/10V	

\* Please select the components taking into consideration the rated voltage, rated current, and ceramic capacitor DC bias characteristics, etc.

\* Use a ceramic capacitor with an execution capacitance value equal to or higher than the recommended component. If a capacitor with a low effective capacitance value is used, the output voltage may become unstable.

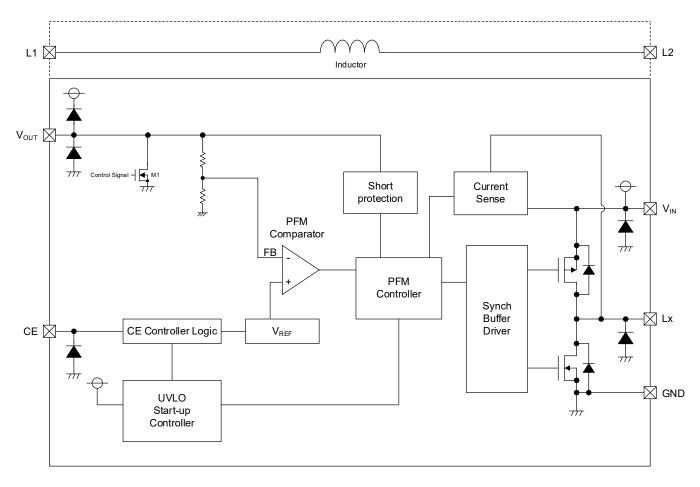
\* Please increase a capacitance value for  $C_L$  in order to reduce output ripple voltages.

CL such as tantalum capacitors which have a larger ESR value can increase output ripple voltages.

If large-capacity capacitors such as electrolytic capacitors are connected in parallel, the inrush current may increase at startup and the output voltage may become unstable.

## ■OPERATIONAL EXPLANATION

The XCL232 series consists of a reference voltage supply, PFM comparator, Pch driver FET, Nch driver FET, current sensing circuit, PFM control circuit, CE control circuit, and others.



< BLOCK DIAGRAM >

The efficiency performance at a light load current is significantly improved compared to existing Torex products by implementing a current limit PFM as a control method and reducing a consumption current by IC itself.

### OPERATIONAL EXPLANATION (Continued)

<Normal operation>

This IC controls the output voltage by adjusting the following 1~3 operation intervals in response to the output current.

The V<sub>OUT1</sub> output voltage average values during actual operation depend on V<sub>OUT1-2</sub> and the ripple voltage during actual operation and are calculated as follows. For this reason, if the ripple voltage changes due to the influence of the input voltage, output voltage, or peripheral components, etc., the output voltage average value will change.

 $V_{OUT1} = V_{OUT1-2} + Ripple Voltage x 1/2$ 

(1) The feedback voltage (FB voltage) is the voltage that results from dividing the output voltage with the V<sub>OUT</sub> Controller logic circuit. The PFM comparator compares this FB voltage to V<sub>REF</sub>. When the FB voltage is lower than V<sub>REF</sub>, the PFM comparator sends a signal to the PFM control circuit to turn on the Pch driver FET.

The On Time to Pch driver FET can be obtained by the following equation.

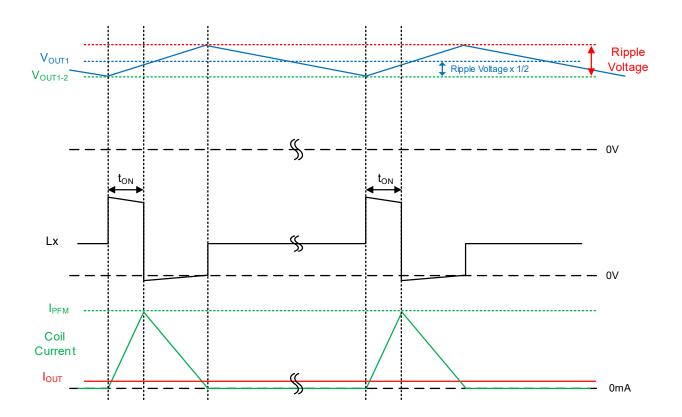
$$t_{ON} = L \times I_{PFM} / (V_{IN} - V_{OUT})$$

(2) When the Pch driver FET turns on, the coil current increases until the coil current reaches PFM Switching Current (IPFM). When the coil current reaches IPFM, the Pch driver FET turns off and then the Nch driver FET turns on.

③ After the Nch driver FET turns on, the coil current will decrease and when the coil current goes down to approx. 0mA, the Nch driver FET will turn off.

The Pch driver FET and Nch driver FET remain off until the FB voltage becomes lower than the reference voltage VREF.

The above  $\bigcirc$   $\bigcirc$  switching operations increase the FB voltage accompanying the output voltage increase, but if the PFM comparator determines the FB voltage is lower than the reference voltage V<sub>REF</sub> before the coil current reaches 0mA, the Nch driver FET turns off and the status moves to  $\bigcirc$ .



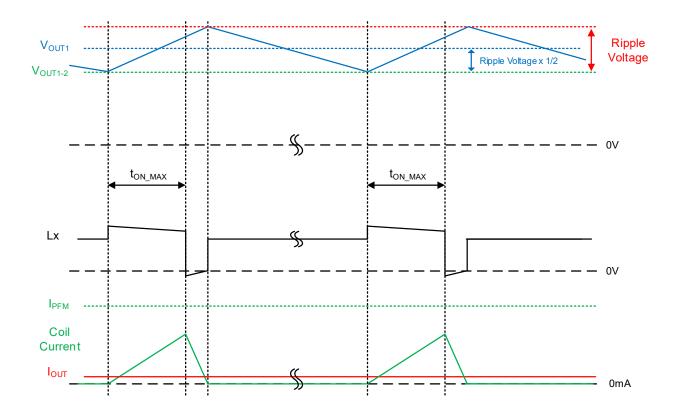
## OPERATIONAL EXPLANATION (Continued)

< Maximum on-time function, 100% Duty operation>

When the input / output potential difference decreases, the on-time required for the coil current to reach  $I_{PFM}$  increases, and the output ripple voltage tends to increase. Therefore, under conditions where the input / output potential difference is small, excessive ripple voltage is suppressed by limiting the maximum on-time that the Pch driver FET can turn on after the FB voltage becomes higher than the reference voltage  $V_{REF}$  to 3.0µs (TYP.).

If the input / output potential difference is further reduced, the FB voltage is always lower than the reference voltage V<sub>REF</sub>, so the 100% duty operation is performed and the Pch driver FET is always on.

At 100% duty, the current consumption of the IC increases compared to normal operation.



## ■OPERATIONAL EXPLANATION (Continued)

#### <CE function>

When "H" voltage (VCEH) is fed to the CE pin, normal operation starts after raising the output voltage with Start-up Mode. When the "L" voltage (VCEL) is fed to the CE pin, it enters the stand-by state and the current consumption is suppressed to 0.0µA (TYP.). Additionally, Pch MOS driver FET and Nch MOS driver FET are turned off.

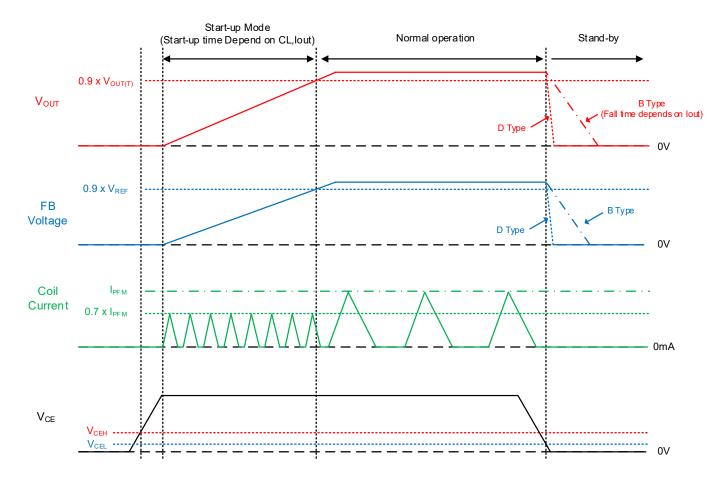
#### <Start-up Mode>

After "H" voltage ( $V_{CEH}$ ) is fed to CE pin and UVLO function is released, by the time when FB voltage goes up to 0.9 x V<sub>REF</sub>, the startup mode operates.

Unlike the normal operation, the start-up mode stops the operation of the short-circuit protection function and prevents the IC from being inadvertently stopped.

In order to suppress the inrush current, the peak current of the coil is limited to 0.7 x IPFM, and the Nch driver FET does not turn on and the coil current flows through the parasitic diode of the Nch driver FET.

The rise time of the output voltage depends on the output capacitance and output current.



#### <UVLO function>

When the  $V_{IN}$  voltage becomes UVLO Detect Voltage ( $V_{UVLOD}$ ) or less, the UVLO function operates to forcibly turn off the Pch MOS driver FET to prevent erroneous pulse output due to operation instability of the internal circuit.

During the UVLO function, the Pch driver FET and Nch driver FET turn off, and the Nch FET M1 between the V<sub>OUT</sub> pin and GND pin turns on to discharge the output capacitance and make the output voltage be lower.

When the  $V_{IN}$  voltage becomes UVLO Release Voltage ( $V_{UVLOR}$ ) or more, the UVLO function is canceled. After the UVLO function is canceled, the output voltage rises with the startup mode, and then the normal operation is performed.

Moreover, during the UVLO operation, the current consumption increases because the internal circuit is operating and the switching operation is stopped, not the stand-by state.

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## OPERATIONAL EXPLANATION (Continued)

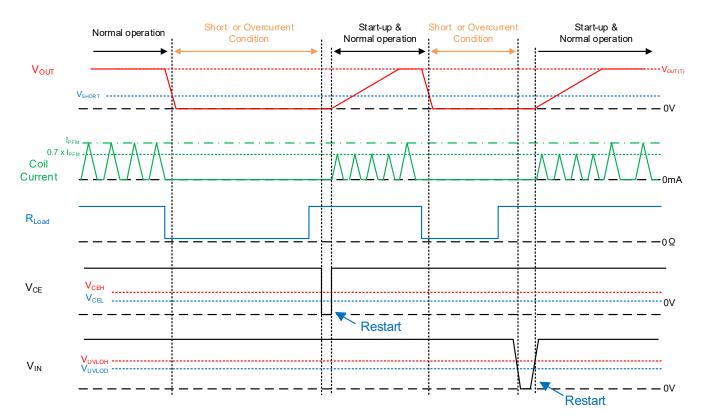
<Short protection function>

#### Case (a) : V<sub>OUT(T)</sub> ≧1.2V

The short-circuit protection function monitors the  $V_{OUT}$  pin voltage, and if the  $V_{OUT}$  pin voltage drops below the Short Protection Threshold Voltage ( $V_{SHORT}$ ) due to a short circuit or overcurrent, the short circuit protection function operates.

When the short-circuit protection function is activated, the Pch driver FET and Nch driver FET are held off. If the  $V_{OUT}$  pin voltage exceeds the Short Protection Threshold Voltage ( $V_{SHORT}$ ) after the short-circuit protection function is activated, normal operation resumes.

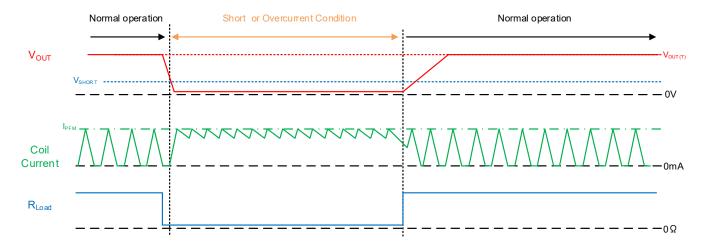
To cancel the short-circuit protection function, it is necessary to start the IC after putting the IC in the standby state with the CE function, or to raise the input voltage after setting the input voltage below the UVLO detection voltage (V<sub>UVLOD</sub>).



•Case (b) : V<sub>OUT(T)</sub> <1.2V

The short-circuit protection function is not implemented in the part numbers where  $V_{OUT(T)}$  is less than 1.2V. If a short circuit or overcurrent occurs, the output voltage will drop and switching operation will continue.

When the short-circuit state or excessive output current is released, the output voltage rises quickly to the set output voltage.



## OPERATIONAL EXPLANATION (Continued)

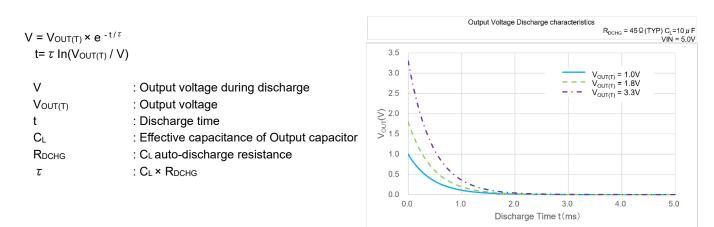
< CL Discharge function (D type)>

On the XCL232 series, a  $C_{\text{L}}$  discharge function is available as an option.

 $C_L$  discharge function turns on the Nch FET M1 between the  $V_{OUT}$  pin and GND pin when the stand-by condition in order to discharge the output capacitance quickly and make the output voltage be lower.

This prevents malfunctioning of the application in the event that a charge remains on  $C_L$  when the IC is stand-by state.

The discharge time is determined by  $C_L$  and the  $C_L$  discharge resistance  $R_{DCHG}$ , including the Nch FET M1. the discharge time of the output voltage is calculated by means of the equation below.



### ■NOTE ON USE

 Be careful not to exceed the absolute maximum ratings for externally connected components and this IC. If it exceeds the absolute maximum rating, it may deteriorate or be destroyed. Also, if used under conditions outside the recommended operating range, the IC may not operate normal

Also, if used under conditions outside the recommended operating range, the IC may not operate normally or may cause deterioration.

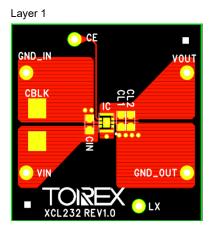
- 2. The DC/DC converter characteristics greatly depend not only on the characteristics of this IC but also on those of externally connected components, so refer to EXTERNAL COMPONENTS SELECTION and the specifications of each component and be careful when selecting the components. Be especially careful of the characteristics of the capacitor used for the load capacity CL and use a capacitor with B characteristics (JIS Standard) or an X7R/X5R (EIA Standard) ceramic capacitor.
- 3. The CE pin does not have an internal pull-up or pull-down, etc. Apply the prescribed voltage to the CE pin. If an intermediate voltage is fed to the CE pins, a through current will flow through the input stage of the CE pins, increasing current consumption.
- 4. At light loads or when IC operation is stopped, leakage current from the Pch driver FET may cause the output voltage to rise.
- 5. Switching operation may be performed continuously due to internal delay or input offset of the PFM comparator circuit. If the switching operation continues, the output ripple voltage increases and the output voltage rises as the ripple voltage increases.
- 6. When the input / output potential difference is small, the ripple voltage increases and the output voltage may increase.
- 7. Since the short-circuit protection function is not implemented in the part number where both of or either V<sub>OUT(T)</sub> is less than 1.2V, the coil current may be superposed under the condition of high input voltage and excessive output current.
- 8. During start-up mode, the peak current of the coil is set lower than in normal operation, so the output voltage may not rise under conditions where the output current is large during start-up.
- 9. To suppress current consumption, UVLO detection is performed only for a certain period after the Pch driver FET is turned on. For this reason, the UVLO function may not operate if the VIN pin voltage instantaneously drops below the UVLO detection voltage (V<sub>UVLOD</sub>).
- 10. Under the conditions of Vin≦2.7V, set output voltage ≤1.0V and Ta≥65°C, the efficiency can drastically drop. Normally after the Nch driver FET turns on, the coil current falls to 0mA, and then Nch driver FET turns off. Under the above conditions, however, before the coil current falls to 0mA, Nch driver FET turns off and its loss increases, which leads to the drop of efficiency.
- 11. This IC is a Inductor Built-in product, do not place it in an environment with a strong magnetic field such as near a magnet. The influence of a strong magnetic field may cause a decrease in inductance value, deterioration of efficiency, and abnormal operation of the IC.
- 12. For temporary, transitional voltage drop or voltage rising phenomenon, the IC is liable to malfunction should the ratings be exceeded.
- 13. Torex places an importance on improving our products and their reliability. We request that users incorporate fail-safe designs and post-aging protection treatment when using Torex products in their systems.

## ■NOTE ON USE (Continued)

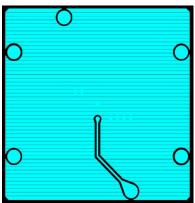
14. Instructions of pattern layouts

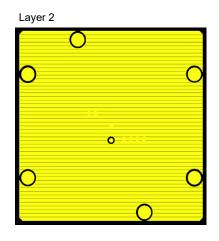
- (1) In order to stabilize V<sub>IN</sub> voltage level, we recommend that a by-pass capacitor (C<sub>IN</sub>) be connected as close as possible to the V<sub>IN</sub> & GND pins.
- (2) Please mount each external component as close to the IC as possible.
- (3) Wire external components as close to the IC as possible and use thick, short connecting traces to reduce the circuit impedance.
- (4) Make sure that the PCB GND traces are as thick as possible, as variations in ground potential caused by high ground currents at the time of switching may result in instability of the IC.
- (5) The IC is a heat-generating component, and heat dissipation measures may be required depending on the conditions of use. If necessary, perform thermal design with PCB layout, etc.

< Reference pattern layout >

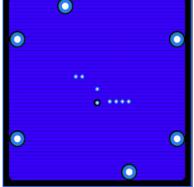


Layer 3





Layer 4



## ■Notes on handling of product

(1) The coil mounted on this product complies with the general surface mount type chip inductor specifications, and may have scratches, flux stains, etc.

(2) Do not use this product in the following environments. Places exposed to water or salt water, places where condensation occurs, places where toxic gases (hydrogen sulfide, zinc acid, chlorine, ammonia, etc.) are present.

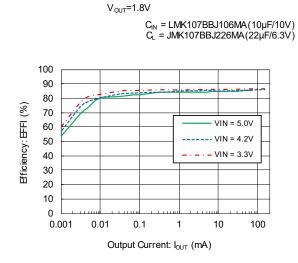
(3) Please do not wash this product with solvent.

### ■Notes on mounting

- (1) Please set the mounting position accuracy within 0.05 mm.
- (2) The proper position of mounting is based on the coil terminal

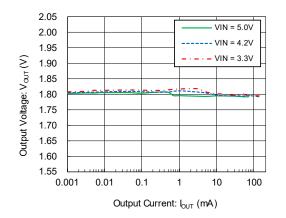
### TYPICAL PERFORMANCE CHARACTERISTICS

#### (1) Efficiency vs. Output Current



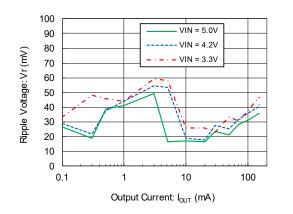
#### (2) Output Voltage vs. Output Current

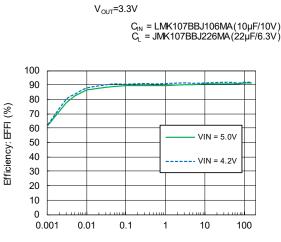
 $V_{OUT}$ =1.8V  $C_{IN}$  = LMK107BBJ106MA(10µF/10V)  $C_{L}$  = JMK107BBJ226MA(22µF/6.3V)



#### (3) Ripple Voltage vs. Output Current

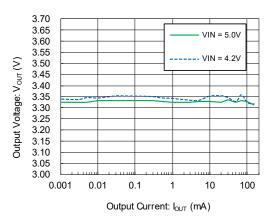


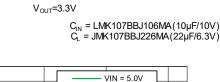


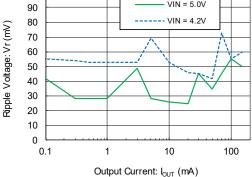


Output Current: I<sub>OUT</sub> (mA)







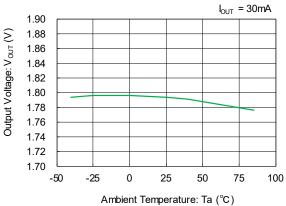


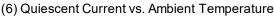
100

## TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

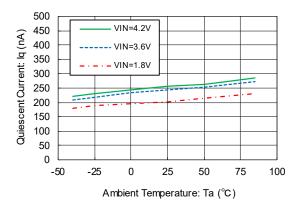
(4) Output Voltage vs. Ambient

V<sub>OUT</sub>=1.8V



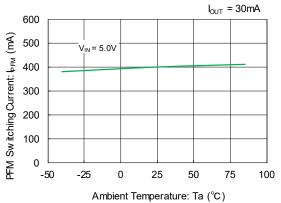


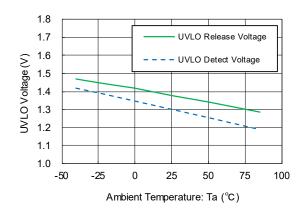
V<sub>OUT</sub>=0.6V



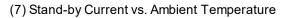
(8) PFM Switching Current vs. Ambient Temperature

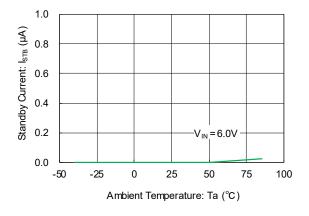
V<sub>OUT</sub>=0.6V  $C_{IN} = LMK107BBJ106MALT(10\mu F/10V)$  $C_L$  = LMK107BBJ106MALT(10µF/10V) × 2



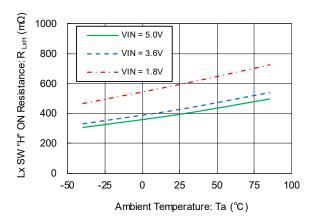


(5) UVLO Voltage vs. Ambient



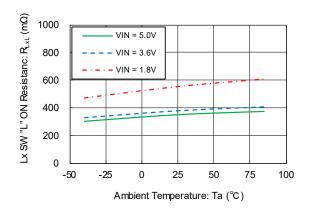


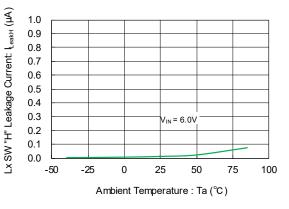
(9) Lx SW "H" ON Resistance vs. Ambient Temperature



### ■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

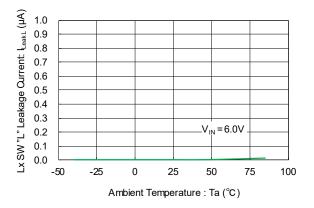
(10) Lx SW "L" ON Resistanc vs. Ambient Temperature (11) Lx SW "H" Leakage Current vs. Ambient Temperature



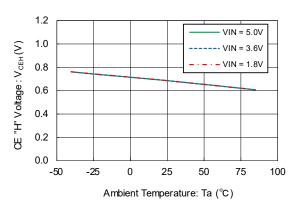


(12) Lx SW "L" Leakage Current vs. Ambient Temperature

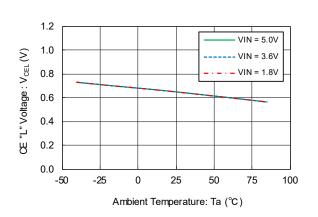
(13) CE "H" Voltage vs. Ambient Temperature

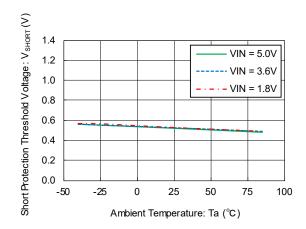


(14) CE "L" Voltage vs. Ambient Temperature



(15) Short Protection Threshold vs. Ambient Temperature

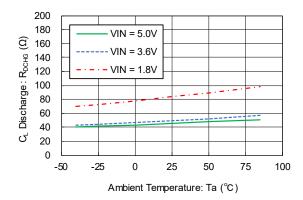




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## TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(16)  $C_L$  Discharge Resistance vs. Ambient Temperature



## ■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

### (17) Load Transient Respones

$$<sup>\</sup>label{eq:V_UV} \begin{split} & V_{\text{OUT}}\text{=}1.8V\\ V_{\text{IN}} = 3.6V \text{ ,} I_{\text{OUT}} = 10\mu\text{A} \Rightarrow 50\text{mA} \text{ ,} tr = 5\mu\text{s}\\ C_{\text{IN}} = LMK107BBJ106MALT(10\mu\text{F}/10V)\\ C_{\text{L}} = LMK107BBJ226MA(22\mu\text{F}/10V) \times 2 \end{split}$$

Ι <sub>ουτ</sub> : 10μΑ	I <sub>OUT</sub> : 50mA ↓
	I <sub>OUT</sub> : 50mA/div
V <sub>OUT</sub> : 200mV/div	20µs/div

### V<sub>OUT</sub>=3.0V

 $\begin{array}{l} \mathsf{V}_{\mathsf{IN}}=3.6\mathsf{V}, \mathsf{I}_{\mathsf{OUT}}=10\mu\mathsf{A}\Rightarrow 50\mathsf{m}\mathsf{A}, \mathsf{tr}=5\mu\mathsf{s}\\ \mathsf{C}_{\mathsf{IN}}=\mathsf{LMK}107\mathsf{BB}\mathsf{J}106\mathsf{M}\mathsf{A}\mathsf{LT}(10\mu\mathsf{F}/10\mathsf{V})\\ \mathsf{C}_{\mathsf{L}}=\mathsf{LMK}107\mathsf{BB}\mathsf{J}226\mathsf{M}\mathsf{A}(22\mu\mathsf{F}/10\mathsf{V})\times 2 \end{array}$ 

Ι <sub>ουτ</sub> : 10μΑ	I <sub>OUT</sub> : 50mA ↓
	l <sub>out</sub> : 50mA/div
V <sub>OUT</sub> : 200mV/div	20µs/div

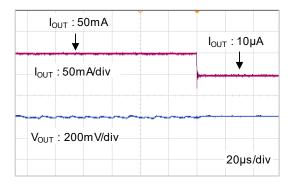
### (18) Startup Mode

V<sub>OUT</sub>=1.8V

$$\begin{split} &\mathsf{V}_{\mathsf{IN}}=3.6\mathsf{V}\;, \mathsf{V}_{\mathsf{CE}}=0.0\mathsf{V} \Rightarrow 3.6\mathsf{V}\;, \mathsf{I}_{\mathsf{OUT}}=50\mathsf{m}\mathsf{A}\;, \mathsf{tr}=5\mu\mathsf{s}\\ &\mathsf{C}_{\mathsf{IN}}=\mathsf{LMK}107\mathsf{BB}\mathsf{J}106\mathsf{MALT}(10\mu\mathsf{F}/10\mathsf{V})\\ &\mathsf{C}_{\mathsf{L}}=\mathsf{LMK}107\mathsf{BB}\mathsf{J}106\mathsf{MALT}(10\mu\mathsf{F}/10\mathsf{V})\;\times2 \end{split}$$

V <sub>CE</sub> : 2V/div	
V <sub>OUT</sub> : 2V/div	
	200µs/div

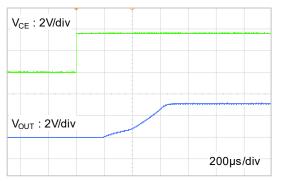
 $\label{eq:V_OUT} \begin{array}{l} V_{\text{OUT}} = 1.8V \\ V_{\text{IN}} = 3.6V \ \text{I}_{\text{OUT}} = 50\text{mA} \Rightarrow 10\mu\text{A} \ \text{,} \text{ff} = 5\mu\text{s} \\ C_{\text{IN}} = \text{LMK107BBJ106MALT}(10\mu\text{F}/10V) \\ C_{\text{L}} = \text{LMK107BBJ226MA}(22\mu\text{F}/10V) \times 2 \end{array}$ 



$$\label{eq:V_OUT} \begin{split} & V_{\text{OUT}}{=}3.0V\\ V_{\text{IN}}{=}3.6V, I_{\text{OUT}}{=}50\text{mA} \Rightarrow 10\mu\text{A}, \text{tf}{=}5\mu\text{s}\\ C_{\text{IN}}{=}LMK107BBJ106MALT(10\mu\text{F}/10V)\\ C_{\text{L}}{=}LMK107BBJ226MA(22\mu\text{F}/10V)\times2 \end{split}$$

I <sub>OUT</sub> : 50mA	Ι <sub>ουτ</sub> : 10μΑ
I <sub>OUT</sub> : 50mA/div	
V <sub>OUT</sub> : 200mV/div	20µs/div

$$\label{eq:V_OUT} \begin{split} &V_{\text{OUT}}{=}3.0\text{V} \\ V_{\text{IN}}{=}3.6\text{V} \ , &V_{\text{CE}}{=}0.0\text{V} \Rightarrow 3.6\text{V} \ , &I_{\text{OUT}}{=}50\text{mA} \ , &tr{=}5\mu\text{s} \\ C_{\text{IN}}{=}\text{LMK107BBJ106MALT}(10\mu\text{F}/10\text{V}) \\ C_{\text{L}}{=}\text{LMK107BBJ106MALT}(10\mu\text{F}/10\text{V}) \ \times 2 \end{split}$$



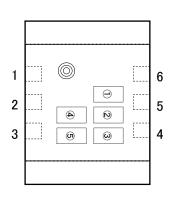
## ■ PACKAGING INFORMATION

For the latest package information go to, www.torexsemi.com/technical-support/packages

PACKAGE	OUTLINE / LAND PATTERN	THERMAL CHARACTERISTICS
CL-2025-03	<u>CL-2025-03 PKG</u>	CL-2025-03 Power Dissipation

### ■MARKING RULE

### •CL-2025-03



### Mark① represents product series.

MARK	PRODUCT SERIES
А	XCL232***1KR-G

### Mark② represents the registered setting, output voltage.

SYMBOL	Туре	OUTPUT VOLTAGE(V)	PRODUCT SERIES
0	В	0.*	XCL232B0*1KR-G
1		1.*	XCL232B1*1KR-G
2		2.*	XCL232B2*1KR-G
3		3.*	XCL232B3*1KR-G
4	D	0.*	XCL232D0*1KR-G
5		1.*	XCL232D1*1KR-G
6		2.*	XCL232D2*1KR-G
7		3.*	XCL232D3*1KR-G

### Mark③ represents the fractional part of the output voltage.

OUTPUT VOLTAGE(V)	SYMBOL	PRODUCT SERIES
*.00	0	XCL232**01KR-G
*.05	А	XCL232**A1KR-G
*.10	1	XCL232**11KR-G
*.15	В	XCL232**B1KR-G
*.20	2	XCL232**21KR-G
*.25	С	XCL232**C1KR-G
*.30	3	XCL232**31KR-G
*.35	D	XCL232**D1KR-G
*.40	4	XCL232**41KR-G
*.45	E	XCL232**E1KR-G
*.50	5	XCL232**51KR-G
*.55	F	XCL232**F1KR-G
*.60	6	XCL232**61KR-G
*.65	Н	XCL232**H1KR-G
*.70	7	XCL232**71KR-G
*.75	К	XCL232**K1KR-G
*.80	8	XCL232**81KR-G
*.85	L	XCL232**L1KR-G
*.90	9	XCL232**91KR-G
*.95	М	XCL232**M1KR-G

Mark④,⑤ represents production lot number

01~09, 0A~0Z, 11~9Z, A1~A9, AA~ZZ, B1~ZZ in order. (G, I, J, O, Q, W excluded) \* No character inversion used.

- 1. The product and product specifications contained herein are subject to change without notice to improve performance characteristics. Consult us, or our representatives before use, to confirm that the information in this datasheet is up to date.
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- 5. Although we make continuous efforts to improve the quality and reliability of our products; nevertheless Semiconductors are likely to fail with a certain probability. So in order to prevent personal injury and/or property damage resulting from such failure, customers are required to incorporate adequate safety measures in their designs, such as system fail safes, redundancy and fire prevention features.
- 6. Our products are not designed to be Radiation-resistant.
- 7. Please use the product listed in this datasheet within the specified ranges.
- 8. We assume no responsibility for damage or loss due to abnormal use.
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